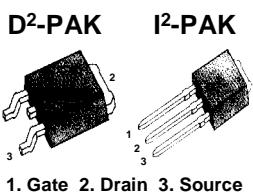


**FEATURES**

- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- 175°C Operating Temperature
- Lower Leakage Current : 10 µA (Max.) @  $V_{DS} = -60V$
- Low  $R_{DS(ON)}$  : 0.362 Ω (Typ.)

$BV_{DSS} = -60 V$   
 $R_{DS(on)} = 0.5\Omega$   
 $I_D = -6.7 A$

**Absolute Maximum Ratings**

Symbol	Characteristic	Value	Units
$V_{DSS}$	Drain-to-Source Voltage	-60	V
$I_D$	Continuous Drain Current ( $T_C=25^\circ C$ )	-6.7	A
	Continuous Drain Current ( $T_C=100^\circ C$ )	-4.7	
$I_{DM}$	Drain Current-Pulsed ①	-27	A
$V_{GS}$	Gate-to-Source Voltage ②	$\pm 30$	V
$E_{AS}$	Single Pulsed Avalanche Energy	115	mJ
$I_{AR}$	Avalanche Current ①	-6.7	A
$E_{AR}$	Repetitive Avalanche Energy ①	3.8	mJ
$dv/dt$	Peak Diode Recovery $dv/dt$ ③	-5.5	V/ns
$P_D$	Total Power Dissipation ( $T_A=25^\circ C$ ) *	3.8	W
	Total Power Dissipation ( $T_C=25^\circ C$ )	38	W
	Linear Derating Factor	0.25	$W/\text{ }^\circ C$
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	- 55 to +175	$^\circ C$
$T_L$	Maximum Lead Temp. for Soldering Purposes, 1/8" from case for 5-seconds	300	

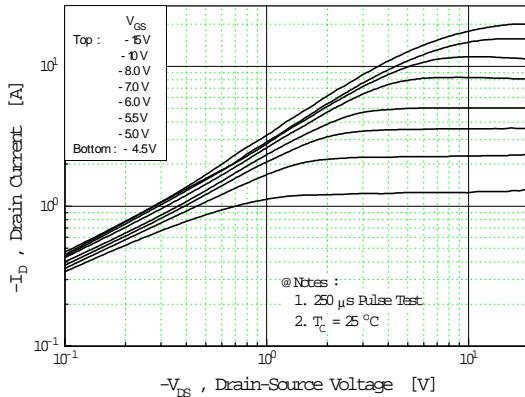
**Thermal Resistance**

Symbol	Characteristic	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case	--	3.95	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient *	--	40	
$R_{\theta JA}$	Junction-to-Ambient	--	62.5	

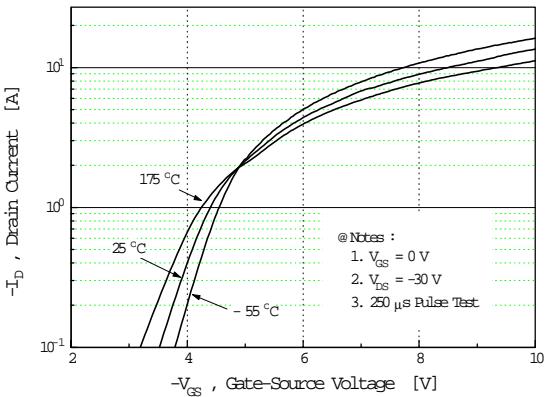
\* When mounted on the minimum pad size recommended (PCB Mount).



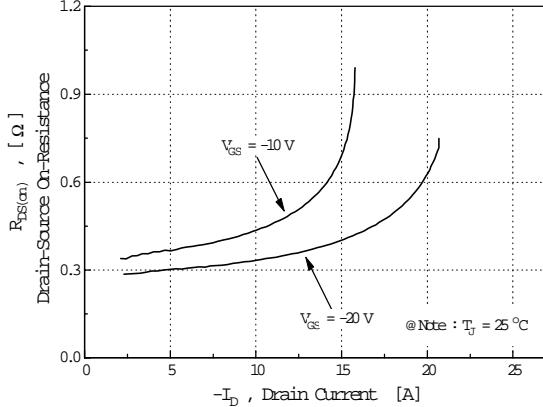
**Fig 1. Output Characteristics**



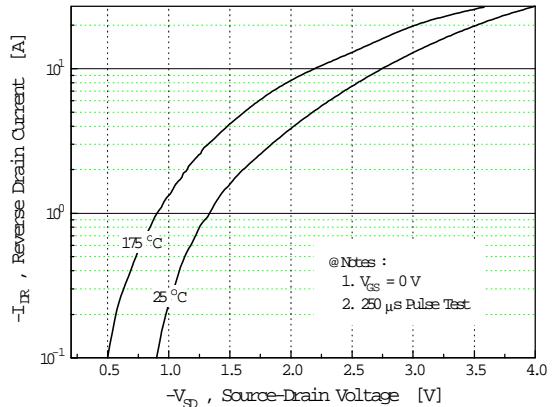
**Fig 2. Transfer Characteristics**



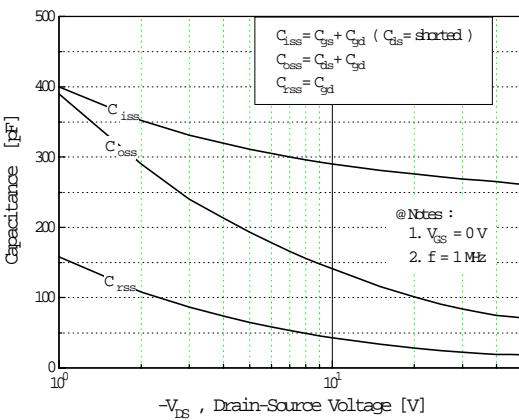
**Fig 3. On-Resistance vs. Drain Current**



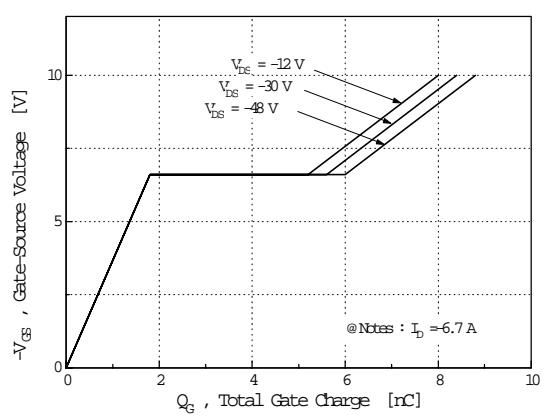
**Fig 4. Source-Drain Diode Forward Voltage**



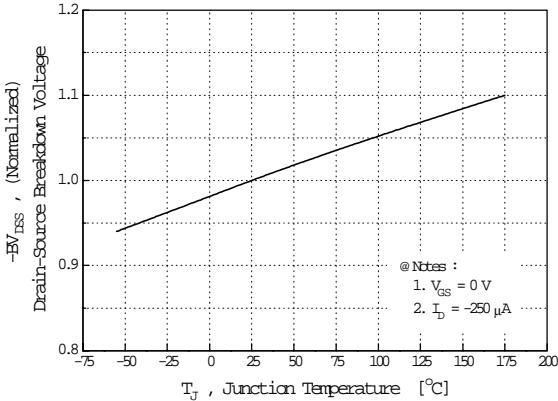
**Fig 5. Capacitance vs. Drain-Source Voltage**



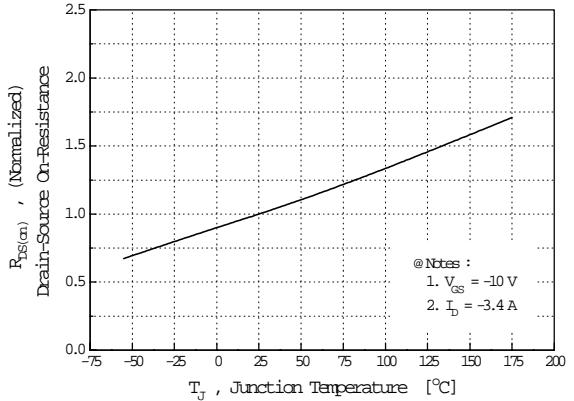
**Fig 6. Gate Charge vs. Gate-Source Voltage**



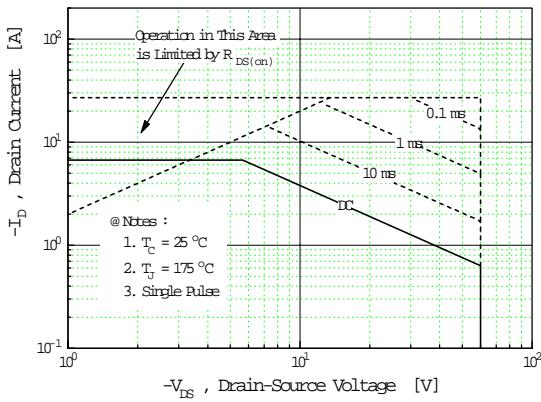
**Fig 7. Breakdown Voltage vs. Temperature**



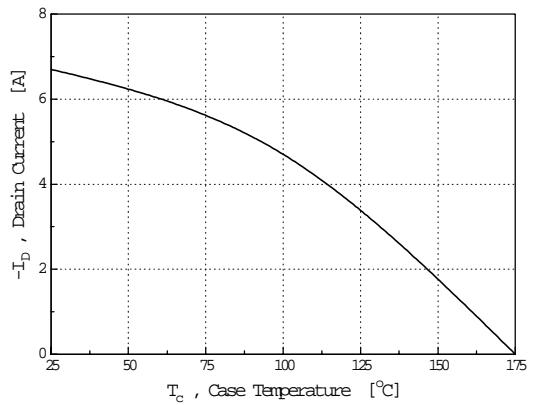
**Fig 8. On-Resistance vs. Temperature**



**Fig 9. Max. Safe Operating Area**



**Fig 10. Max. Drain Current vs. Case Temperature**



**Fig 11. Thermal Response**

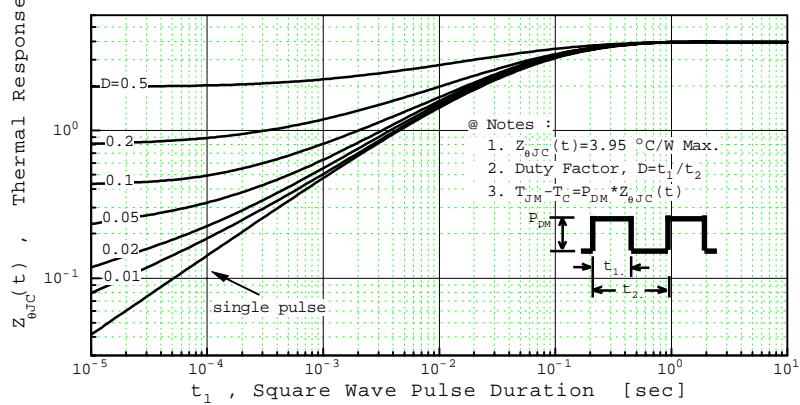


Fig 12. Gate Charge Test Circuit & Waveform

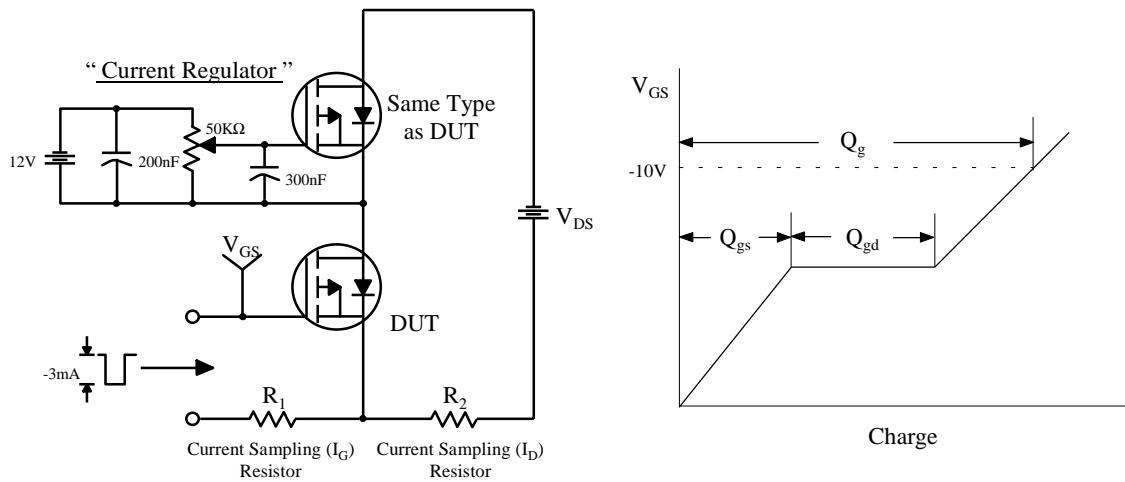


Fig 13. Resistive Switching Test Circuit & Waveforms

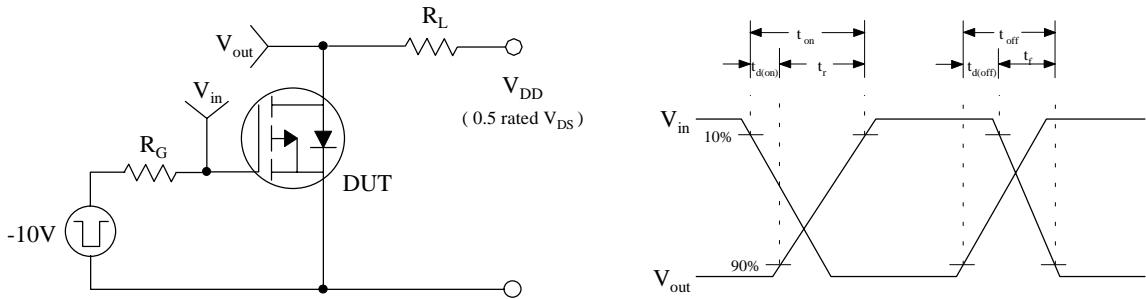


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

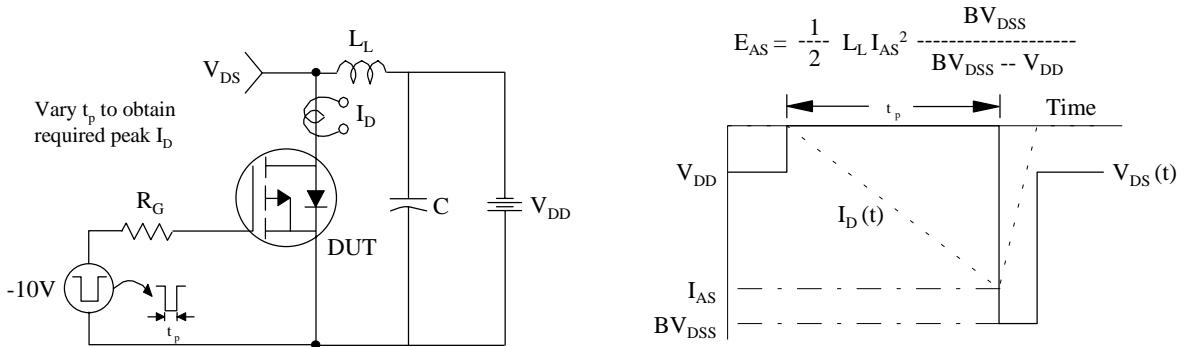
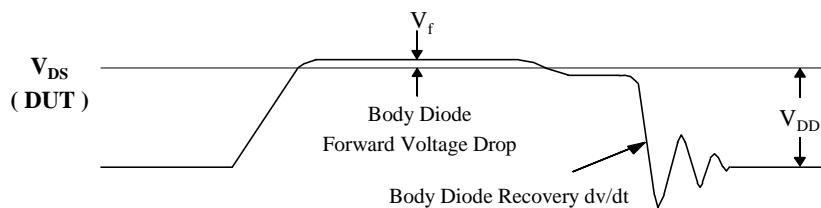
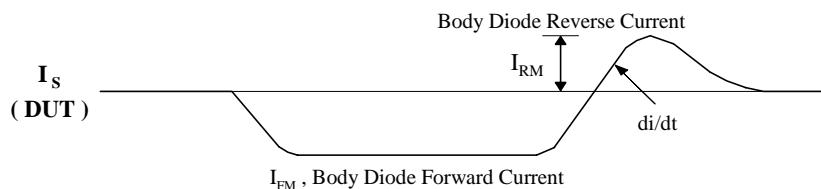
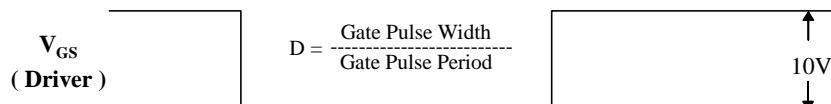
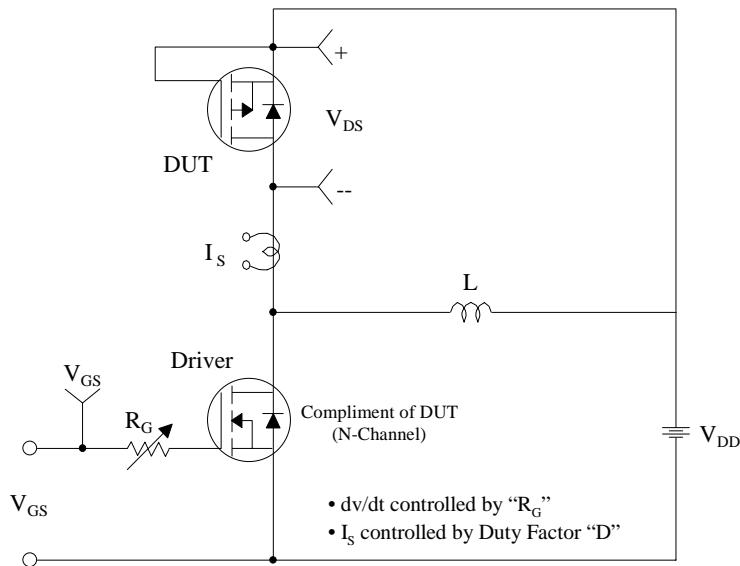


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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EnSigna™	I <sup>2</sup> C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™	OCXPro™	OPTOLOGIC®	RapidConnect™	UltraFET®
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